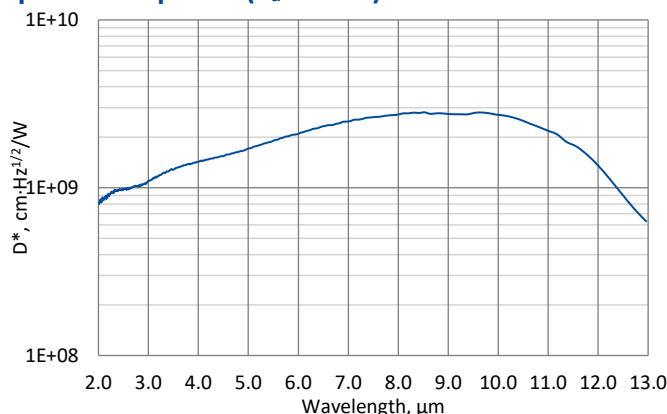


SM-I-12

2.0 – 14.0 μm and 10 Hz – 1 MHz HgCdTe small-size IR detection module with optically immersed photoconductive detector

SM-I-12 is an ultra-small IR detection module. Thermoelectrically cooled, optically immersed photoconductive detector, based on HgCdTe heterostructure (PCI-3TE-12-1 \times 1-TO8-wZnSeAR-36) is integrated with transimpedance, AC coupled preamplifier. There is a possibility to manually adjust gain of the signal. 3° wedged zinc selenide anti-reflection coated window prevents unwanted interference effects. SM-I-12 is easy to assembly in space limited measuring systems of FTIR applications.

Spectral response ($T_a = 20^\circ\text{C}$)



Exemplary spectral detectivity, the spectral response of delivered devices may differ.



Specification ($T_a = 20^\circ\text{C}$)

Parameter	Typical value
Optical parameters	
Cut-on wavelength $\lambda_{\text{cut-on}}$ (10%), μm	≤ 2.0
Peak wavelength λ_{peak} , μm	10.0 ± 0.2
Optimum wavelength λ_{opt} , μm	12.0
Cut-off wavelength $\lambda_{\text{cut-off}}$ (10%), μm	14.0 ± 0.2
Detectivity D^* (λ_{peak} , 20 kHz), $\text{cm} \cdot \text{Hz}^{1/2} / \text{W}$	$\geq 2.5 \times 10^9$
Detectivity D^* (λ_{opt} , 20 kHz), $\text{cm} \cdot \text{Hz}^{1/2} / \text{W}$	$\geq 1.3 \times 10^9$
Output noise density v_n (20 kHz), $\mu\text{V} / \text{Hz}^{1/2}$	≤ 6
Electrical parameters	
Voltage responsivity R_v (λ_{peak} , 100 kV/A), V/W	$\geq 1.35 \times 10^5$
Voltage responsivity R_v (λ_{opt} , 100 kV/A), V/W	$\geq 6.30 \times 10^4$
Voltage responsivity R_v (λ_{peak} , 55 kV/A), V/W	$\geq 7.45 \times 10^4$
Voltage responsivity R_v (λ_{opt} , 55 kV/A), V/W	$\geq 3.45 \times 10^4$
Low cut-off frequency f_{lo} , Hz	10
High cut-off frequency f_{hi} , Hz	$1\text{M} \pm 0.1$
Output impedance R_{out} , Ω	50
Output voltage swing V_{out} , V	10 ($R_L = 1 \text{M}\Omega^*$)
Output voltage offset V_{off} , mV	max ± 20
Other information	
Active element material	epitaxial HgCdTe heterostructure
Optical area A_o , mm \times mm	1 \times 1
Window	wZnSeAR
Acceptance angle Φ	$\sim 36^\circ$
Ambient operating temperature T_a , $^\circ\text{C}$	10 to 30
Signal output socket	MMCX
Power supply and TEC control socket	AMPMODU 2 \times 4 (male)
Mounting hole	none
Fan	no (external heatsink necessary)

* R_L – load resistance

Features

- Wide spectral range from 2.0 to 14.0 μm
- High responsivity
- Large dynamic range
- Very small size
- Convenient to use
- Quantity discounted price
- Fast delivery

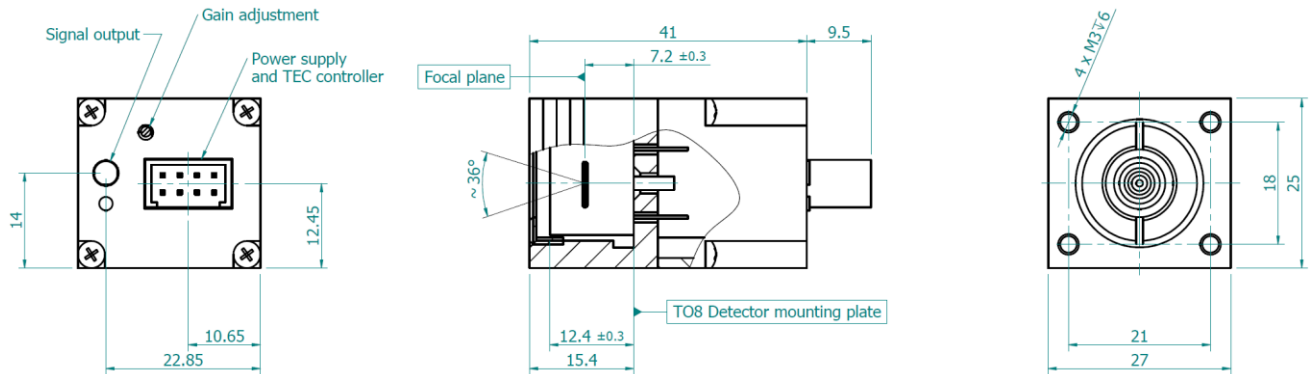
Applications

- FTIR spectroscopy and spectrometry

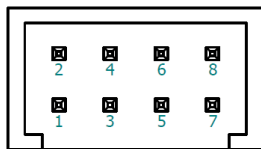
Related product

- PCI-3TE-12-1 \times 1-TO8-wZnSeAR-36

Mechanical layout, mm

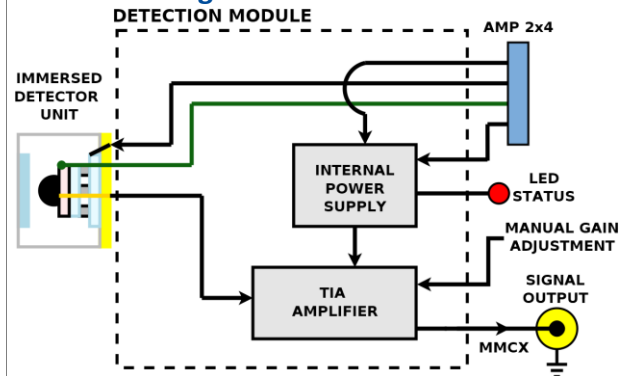


Power supply and TEC control socket AMPMODU 2x4 (male)



Function	Symbol	Pin number
Power supply input (-)	-V _{sup}	1
Thermistor output	TH2	2
Data pin	DATA	3
TEC supply input (-)	TEC-	4
Ground	GND	5
Thermistor output	TH1	6
Power supply input (+)	+V _{sup}	7
TEC supply input (+)	TEC+	8

Schematic diagram



Included accessories

- **MMCX-BNC, AMP2x4-DB9** cables

Dedicated accessories

- **PTCC-01-BAS** TEC controller + **USB: TypeA-MicroB** cable + **AC adaptor**
- **PTCC-01-ADV** TEC controller + **USB: TypeA-MicroB** cable + **AC adaptor**
- **PTCC-01-OEM** TEC controller + **USB: TypeA-MicroB, KK2-POWER** cables
- **MHS-2** heatsink